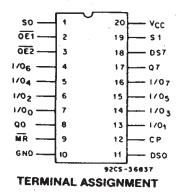


SCHS288

CD54/74AC299, CD54/74AC323 CD54/74ACT299, CD54/74ACT323



8-Input Universal Shift/Storage Register with Common Parallel I/O Pins

CD54/74AC/ACT299 - Asynchronous Reset CD54/74AC/ACT323 - Synchronous Reset

Type Features:

Buffered inputs

Typical propagation delay:

6 ns @ V_{CC} = 5 V, T_A = 25° C, C_L = 50 pF

The RCA CD54/74AC299 and CD54/74AC323 and the CD54/74ACT299 and CD54/74ACT323 are 3-state, 8-input universal shift/storage registers with common parallel I/O pins. These devices use the RCA ADVANCED CMOS technology. These registers have four synchronous-operating modes controlled by the two select inputs as shown in the Mode Select (S0, S1) table. The Mode Select, the Serial Data (DSO, DS7), and the Parallel Data (I/O₀ - I/O₇) respond only to the LOW-TO-HIGH transition of the clock (CP) pulse. S0, S1 and Data inputs must be present one setup time prior to the positive transition of the clock.

With the CD54/74AC/ACT299, the Master Reset (\overline{MR}) is an asynchronous active-LOW input. When \overline{MR} is LOW, the register is cleared regardless of the status of all other inputs. With the CD54/74AC/ACT323, the Master Reset (\overline{MR}) clears the register in sync with the clock input. The register can be expanded by cascading same units by tying the serial output (QO) to the serial data (DS7) input of the preceding register, and tying the serial output (Q7) to the serial data (DSO) input of the following register. Recirculating the (n x 8) bits is accomplished by tying the Q7 of the last stage to the DSO of the first stage.

The 3-state input/output (I/O) port has three modes of operation:

- 1. Both Output Enable (OE1 and OE2) inputs are LOW and S0 or S1 or both are LOW; the data in the register is present at the eight outputs.
- 2. When both S0 and S1 are HIGH, I/O terminals are in the high-impedance state but being input ports, ready for parallel data to be loaded into eight registers with one clock transition regardless of the status of OE1 and OE2.

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
 Fanout to 15 FAST* ICs
 Drives 50-ohm transmission lines

*FAST is a Registered Trademark of Fairchild Semiconductor Corp.

3. Either one of the two Output Enable inputs being HIGH will force I/O terminals to be in the off state. It is noted that each I/O terminal is a 3-state output and a CMOS buffer input.

The CD74AC/ACT299 and CD74AC/ACT323 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT299 and CD54AC/ACT323, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

This data sheet is applicable to the CD54/74AC299, CD74AC323, CD54/74ACT299, and CD54ACT323. The CD54AC323 and CD74ACT323 were not acquired from Harris Semiconductor.

File Number 1958

MODE SELECT - FUNCTION TABLE REGISTER OPERATING MODES

				INPUTS	S			REGISTER OUTPUTS				
FUNCTION	MR	СР	SO	S1	DS0	DS7	I/On	Q0	Q1	• • •	Q6	Q7
Reset (Clear)	L -	X*	Х	X	X	X	X	L	L		Ľ	Ł
Shift Right	• H •	_	h	1	1	X	X	L	qo		Q5	Q6
	<u>н</u>		h	1	h	X	(X	н	qo		Q5	Q ₆
Shift Left	н	·/	1	h	×	1	X	q 1	q2		Q7	L
	H			h	X	h	X	q1	q2		q,	н
Hold (do nothing)	н		1	1	X	X	X	qo	q1		q ₆	Q7
Parallel Load	н		h	h	X	X		L	L		L	L
	н		h	h	X	x	h	н	н		н	н

*On CD54/74AC/ACT323, CP must be in transition from the LOW-to-HIGH state to Reset (Clear).

MODE SELECT -- FUNCTION TABLE 3-STATE I/O PORT OPERATING MODE

FUNCTION			INPUTS/OUTPUTS			
FUNCTION	OE1	OE2	S0	S1	Qn (Register)	I/O ₀ I/O ₇
Read Register	L	L	L	X	L	L
	L	L	L	X	н	н
	L	L	x	L	L	L
	L	L	x	L	н	Н
Load Register	X	х	н	н	Qn = I/On	I/On = Inputs
Disable I/O	н	Х	X	X	X	(Z)
	X	н	x	X	Х	(Z)

H = Input voltage high level.

h = Input voltage high one set-up time prior clock transition.

L = Input voltage low level.

I = Input voltage low one set-up time prior clock transition.

qn = Lower case letters indicate the state of the referenced output one set-up time prior clock transition.

X = Voltage level on logic status don't care.

 \underline{Z} = Output in high-impedance state.

= Low-to-high clock transition.

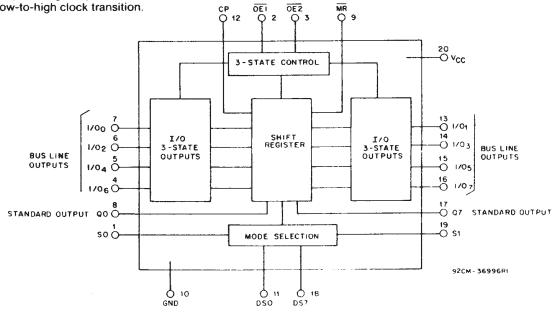


Fig. 1 - Functional diagram

CD54/74AC299, CD54/74AC323 CD54/74ACT299, CD54/74ACT323

MAXIMUM RATINGS, Absolute-Maximum Values:

$\begin{array}{l} \mbox{DC SUPPLY-VOLTAGE (V_{cc})} \\ \mbox{DC INPUT DIODE CURRENT, } I_{IK} (for V_1 < -0.5 V or V_1 > V_{cc} + 0.5 V) \\ \mbox{DC OUTPUT DIODE CURRENT, } I_{oK} (for V_o < -0.5 V or V_o > V_{cc} + 0.5 V) \\ \mbox{DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, } I_o (for V_o > -0.5 V or V_o \\ \mbox{DC V}_{cc} or GROUND CURRENT (I_{cc} or I_{GND}) \\ \end{array}$	
POWER DISSIPATION PER PACKAGE (PD):	
For $T_A = -55$ to $\pm 100^{\circ}$ C (PACKAGE TYPE E)	
For $T_A = +100$ to $+125^{\circ}C$ (PACKAGE TYPE E)	Derate Linearly at 8 mW/°C to 300 mW
For $T_A = -55$ to $+70^{\circ}$ C (PACKAGE TYPE M)	
For $T_A = +70$ to $+125^{\circ}C$ (PACKAGE TYPE M)	. Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T _A)	55 to +125°C
STORAGE TEMPERATURE (T _{sta})	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79$ mm) from case for 10 s maximum	+265°C
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contactin	
*For up to 4 outputs per device; add \pm 25 mA for each additional output.	

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

	LIN	1141170	
CHARACTERISTICS	MIN.	MAX.	
Supply-Voltage Range, Vcc*:			
(For T _A = Full Package-Temperature Range)			
AC Types	1.5	5.5	V
ACT Types	4.5	5.5	V
DC Input or Output Voltage, Vi, Vo	0	Vcc	V
Operating Temperature, T _A	-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv			1
at 1.5 V to 3 V (AC Types)	0	50	ns/V
at 3.6 V to 5.5 V (AC Types)	0	20	ns/V
at 4.5 V to 5.5 V (ACT Types)	0	10	ns/V

*Unless otherwise specified, all voltages are referenced to ground.

9

STATIC ELECTRICAL CHARACTERISTICS: AC Series

	<u>.</u>							RATURE	(T _A) - °(C	
CHARACTERIST	ICS	TEST CO	NDITIONS	V _{cc}	+	25	-40 t	o +85.	-55 to	o +125	UNITS
		V, (V)	l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	ViH			1.5 3 5.5	1.2 2.1 3.85		1.2 2.1 3.85		1.2 2.1 3.85	-	v
Low-Level Input Voltage	ViL			1.5 3 5.5		0.3 0.9 1.65		0.3 0.9 1.65		0.3 0.9 1.65	v
High-Level Output			-0.05	1.5	1.4		1.4	_	1.4	-	
Voltage	Vон	ViH	-0.05	3	2.9	_	2.9		2.9		1
		or	-0.05	4.5	4.4		4.4	—	4.4	-]
		VIL	-4	3	2.58	—	2.48	—	2.4	—] V
			-24	4.5	3.94		3.8	—	3.7	-	
		#, * {	-75	5.5		—	3.85	—	_		
		<i>""</i>	-50	5.5	—	_			3.85	-	
Low-Level Output			0.05	1.5	_	0.1		0.1		0.1	
Voltage	VOL	ViH	0.05	3		0.1		0.1		0.1	
		or	0.05	4.5		0.1		0.1		0.1]
		ViL	12	3		0.36		0.44	_	0.5	V
			24	4.5		0.36		0.44	—	0.5	
		#, * {	75	5.5		_		1.65			
		<u> </u>	50	5.5						1.65	
Input Leakage Current	t _i	V _{cc} or GND		5.5	_	±0.1	_	· ±1	—	±1	μA
3-Stage Leakage Current	loz	VIH or VIL Vo= Vcc or GND		5.5		±0.5		±5		±10	μA
Quiescent Supply Current, MSI	t _{cc}	V _{cc} or GND	0	5.5	—	8		80		160	μA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation. *Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

_ Technical Data

CD54/74AC299, CD54/74AC323 CD54/74ACT299, CD54/74ACT323

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

						AMBIEN	Т ТЕМРЕ	RATURI	E (T _A) - °	с	
CHARACTERIST	ICS	TEST CO	NDITIONS	V _{cc} (V)	+	25	-40 to +85		-55 to +125		UNITS
		V, (V)	/, I _o /) (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	ViH			4.5 to 5.5	2	_	2	_	2	_	v
Low-Level Input Voltage	VIL			4.5 to 5.5		0.8	_	0.8		0.8	v
High-Level Output	ViH	-0.05	4.5	4.4	—	4.4		4.4			
Voltage	V _{он}	or V _{IL}	-24	4.5	3.94		3.8	-	3.7]
		#, * {	-75	5.5	—	—	3.85	-	—	[_	V
		<u>"'</u>	-50	5.5	_				3.85	—]
Low-Level Output		ViH	0.05	4.5		0.1	-	0.1	-	0.1	
Voltage Vol	VOL	or V⊫	24	4.5		0.36		0.44		0.5	l v
		#, * {	75	5.5		_	_	1.65	-	_	1
		" , " [50	5.5		_			_	1.65	1
Input Leakage Current	h	V _{cc} or GND		5.5		±0.1	_	±1	·	±1	μA
3-State Leakage Current	loz	V _{IH} or V⊾ Vo Vcc or GND		5.5		±0.5		±5		±10	μΑ
Quiescent Supply Current, MSI	lcc	V _{cc} or GND	0	5.5	—	8	_	80	_	160	μΑ
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load	Supply in ∆l _{cc}	V _{cc} -2.1		4.5 to 5.5		2.4	_	2.8	—	3	mA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation. *Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

,

	UNIT LOADS*				
INPUT	299	323			
S1, S0, OE1, OE2	0.83	0.83			
1/0º - 1/01, CP, DS0, DS7	0.67	0.67			
MR	1.33	0.67			

ACT INPUT LOADING TABLE

*Unit load is Alcc limit specified in Static

Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

9

PREREQUISITE FOR SWITCHING: AC Series

			AMBI	ENT TEMPE	RATURE (1	(1.
CHARACTERISTICS	SYMBOL	V _{cc}	-40 t	o +85	-55 te	+125	
		(V)	MIN.	MAX,	MIN.	MAX.	1
Setup Time S1, S0, to CP	tsu	1.5 3.3*	99 11.1		113 12.6		ns
Hold Time S1, S0 to CP	te	5† 1.5 3.3 5	7.9 0 0 0		9 0 0 0		ns
Setup Time (I/O)n, DS0, DS7 to CP	tsu	1.5 3.3 5	49 5.5 3.9		56 6.3 4.5		ns
Hold Time (I/O)n, DS0, DS7 to CP	tsu	1.5 3.3 5	0 0 0		0 0 0	 	ns
Setup Time MR to CP (323)	tsu	1.5 3.3 5	61 6.8 4.8	-	69 7.8 5.5		ńs
Hold Time MR to CP (323)	tH	1.5 3.3 5	0 0 0		0 0 0		ns
Maximum CP Frequency	fmax	1.5 3.3 5	9 78 108	-	8 68 95	-	MHz
CP Pulse Width	tw	1.5 3.3 5	57 6.4 4.6		65 7.3 5.2		ns
MR Pulse Width	tw	1.5 3.3 5	55 6.1 4.4		63 7 5		ns
Recovery Time MR to CP 299	trec	1.5 3.3 5	55 6.1 4.4		63 7 5		ns

*3.3 V: min. is @ 3 V †5 V: min is @ 4.5 V

		••	AMBI	ENT TEMPE	RATURE (1	۲ _۸) - °C	
CHARACTERISTICS	SYMBOL	V _{cc}		lo +85	-55 to		
-		(V)	MIN.	MAX.	MIN.	MAX.	
Propagation Delays: CP to Q0, Q7	t _{РСН.} t _{PHL}	1.5 3.3* 5†		147 16.5 11.7		162 18.1 12.9	ns
CP to (I/O)n	tрін tрні	1.5 3.3 5	 4.9 3.5	154 17.2 12.3	 4.7 3.4	169 18.9 13.5	ns
MR to Q0, Q7 (299 only)	tрін tрні	1.5 3.3 5	 4 2.9	127 14.3 10.2	 3.9 2.8	140 15.7 11.2	ns
MR to (I/O)n	tplн tphl	1.5 3.3 5		158 17.7 12.6	 4.9 3.5	174 19.5 13.9	ns
Enable and Disable Times	tpzl tpzh tplz tplz tphz	1.5 3.3 5	— 5.8 3.8	169 20.4 13.5	 5.6 3.7	186 22.4 14.9	ns
Power Dissipation Capacitance	Cpd§		280	Тур.	280	pF	
Input Capacitance	Cı	_	_	10		10	pF
3-State Output Capacitance	Co	_	_	15	_	15	pF

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SWITCHING CHARACTERISTICS: AC Series; tr, tr = 3 ns, CL = 50 pF

*3.3 V: min. is @ 3.6 V

max. is @ 3 V

†5 V: min. is @ 5.5 V

§CPD is used to determine the dynamic power consumption, per function. $P_D = C_{PD}V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o)$ where $f_i = input$ frequency

max. is @ 4.5 V

 $f_o = output frequency$ $C_L = output load capacitance$ $V_{CC} = supply voltage.$

PREREQUISITE FOR SWITCHING: ACT Series

		V _{cc} (V)	AMBI	1			
CHARACTERISTICS	SYMBOL		-40 to +85		-55 t		
· · · · · · · · · · · · · · · · · · ·			MIN.	MAX.	MIN.	MAX.	1
Setup Time S1, S0 to CP	tsu	5*	7.9	-	9		ns
Hold Time S1, S0 to CP	tíi	5	0		0	_	ns
Setup Time (I/O)n, DS0, DS7 to CP	tsu	5	3.9		4.5		ns
Hold Time (I/O)n, DS0, DS7 to CP	tн	5	0	_	0	_	ns
Setup Time MR to CP (323)	tsu	5*	4.8	-	5.5		ns
Hold Time MR to CP (323)	tн	5	0	_	0	-	ns
Maximum CP Frequency	fmax	5	103	_	90		MHz
CP Pulse Width	tw	5	4.8		5.5	_	ns
MR Pulse Width	tw	5	4.4		5	_	ns
Recovery Time MR to CP (299)	trec	5	4.4	_	5	—	ns

*5 V: min. is @ 4.5 V

SWITCHING CHARACTERISTICS: ACT Series; t,, tr = 3 ns, CL = 50 pF

		V _{cc} (V)	AMBI				
CHARACTERISTICS	SYMBOL		-40 to +85		-55 to	UNITS	
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: CP to Q0, Q7	t _{РСН} трыс	5*	3.3	11.7	3.2	12.9	ns
CP to (I/O)n	t _{РЕН}	5	* 3.7	13.2	3.6	14.5	'ns
MŘ to Q0, Q7 (299 only)	t _{РLН} tрні	5	3.1	11.1	3.1	12.2	ns
MR to (I/O)n	tрін Трні	5	4.8	16.9	4.7	18.6	ns
Enable and Disable Times	tpiz tpнz tpzi tpzi	5	3.8	13.5	3.7	14.9	ns
Power Dissipation Capacitance	CPD§		280	Тур.	280	Тур.	рF
Input Capacitance	Cı		_	10		10	pF
3-State Output Capacitance	Co			15	_	15	pF

*5 V: min. is @ 5.5 V max. is @ 4.5 V $\label{eq:cp} \begin{array}{l} \label{eq:cp} \ensuremath{\S{C_{PD}}} is used to determine the dynamic power consumption, per function. \\ P_D = C_{PD} V_{CC}{}^2 f_i + \Sigma \; (C_L V_{CC}{}^2 f_o) + V_{CC} \Delta I_{CC} \; where \; f_i = input \; frequency \\ f_o = output \; frequency \end{array}$

 $C_L = output load capacitance$

 $V_{cc} = supply voltage.$

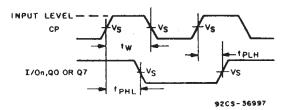


Fig. 2 - Clock prerequisite and propagation delays.

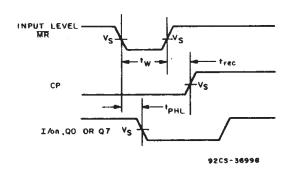
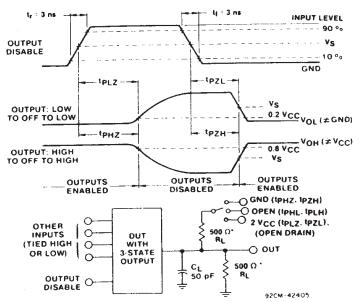


Fig. 3 - Master Reset prerequisite and propagation delays.



*FOR AC SERIES ONLY: WHEN VCC = 1.5 V, RL = 1 k\Omega

Fig. 4 - Three-state propagation delay times and test circuit.

_ Technical Data

CD54/74AC299, CD54/74AC323 CD54/74ACT299, CD54/74ACT323

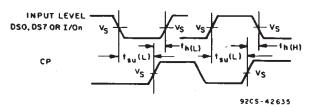
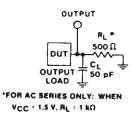


Fig. 5 - Data prerequisite times.



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Fig. 6 - Test circuit.

	CD54/74AC	CD54/74ACT	
Input Level	Vcc	3 V	
Input Switching Voltage, Vs	0.5 Vcc	1.5 V	
Output Switching Voltage, Vs	0.5 Vcc	0.5 V _{cc}	

9

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54AC299F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT299F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT323F3A	NRND	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD74AC299M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC299M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC323M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT299M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT299M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT299M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



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